SWITCHES GAAS

SPDT DC to 4.6 GHz



MODEL◆ NO.	FREQ. (GHz)	ABSORPTIVE	REFLECTIVE	А	В.	cy band	C₂ Typ. Max.	freq A	OMPF (dBm) uency B Typ.			(dB) equency ba B Typ. Min.	nd C	CASE STYLE	CONNECT-ON	PRICE \$ Qty. (1-9)
												F0 10	10 00	1/1/4440		01.05
KSW-2-46	DC-4.6			0.9 1.1	1.0 1.3	1.3 1.8	2.0 2.8	10	1/	27	60 50	50 40	40 28	XX112	eh	36.95

A = DC to 200MHz

B = 200MHz to 1000MHz

C = 1000MHz to 4600MHz

C₁= 1000MHz to 3000MHz

 $C_{2} = 3000MHz$ to 4600MHz

additional specifications

Model Series	KSW	KSWA	MSW	MSWA	MSWT			
Control Voltage			-8/0 for compres	ssion spec, -8 to -5/0 fo	r all other spe	CS		
Control Current, mA	2.5 typ.	at -8V	0.2 max to -8V, 0	0.02 max at 0 to -0.2V				
			DC-1GHz	1-2GHz	DC1GHz	.15GHz	.5-1GHz	1-2GHz
VSWR (:1)	1.3 typ.		1.2 typ.	1.4 typ.	1.2	1.25	1.4	1.4
				1.45	1.65	1.8	1.9	1.7
Rise/ Fall time (10% - 90%), ns	2 typ.		2 typ.	3 typ.	2 typ.			
Switching time, 50% of Control to								
90% RF (Turn-on), ns			4 typ.	5.5 typ.	4 typ.			
10% RF (Turn-off), ns			4 typ.	3 typ.	4 typ.			
**Video Leakage, mVp-p	30 typ.		15 typ.	8 typ.	15 typ.			
0/-5V Control								
Temperature, °C operating	-55 to 10	00		-40 to 85				
storage	-55 to 15	0		-55 to 100				
MTBF, hrs @100°C case	7X10 ⁶	11X10 ⁶						

NOTES:

- Aqueous washable.
- KSWA model is hermetically sealed.
- Video leakage or break through is defined as leakage of TTL switching signal to RF output ports.
- Environmental specifications and re-flow soldering information available in General Information
- Units are non-hermetic unless otherwise noted. For details on case dimensions & finishes see "Case Styles & Outline Drawings".
- Prices and Specifications subject to change without notice.
- Absolute maximum power, voltage and current ratings for KSW, KSWA models:
 - 1a. RF power input, +30 dBm except below 500 MHz +27 dBm;
 - 1b. Control voltage -10 V maximum.
- Absolute maximum power, voltage & current ratings; MSW, MSWA MSWT models;

۷.	Absolute maxim	um power, voltage & curre	ntraung	5. IVISVV, I	VIOVA IVIOV	viiilou
2a.	RF power input,	(25°C)	DC-100	100-500	500-2000	MHz
	MSW-2-20:	Steady state 0/-8V control	+23	+27	+31	dBm
		As modulator	+11	+17	+21	dBm
	MSWA-2-20:	Steady state 0/-8V control	+24	+27	+33	dBm
		As modulator	+12	+17	+23	dBm
	MSWT-4-20:	Steady state 0/-8V control	+24	+27	+33	dBm
		modulator application	+12	+17	+23	dBm

2b. Control current, 500µA (Occurs at -9V to -12V typical)

For reflective switches, KSW, MSW, RSW models, OFF state of RF output is low impedance.

NSN GUIDE MCL NO.

5985-01-393-7219 KSW-2-46

5985-01-369-4224 KSWA-2-46



SPDT DC to 2 GHz



MODELA	FREQ. (GHz)	ORPTIVE	LECTIVE	INSERTION LOSS (dB) frequency band					1 dB COMPRESSION (dBm) frequency band				IN-OUT ISOLATION (dB) frequency band						CASE STYLE	HOMZZOO	PRICE \$
MODEL◆ NO.	f _L - f _U	ABS	REFI	A Typ. Max.	B Typ. Max.	C Typ. Max.	D Typ. Max.	А Тур.	B Typ.	C Typ.	D Typ.		A Max.	B Typ. Max.	Тур.	C Max.	Typ.	Max.	Note B	0 N	Qty. (10)
MSW-2-20 MSWA-2-20	DC-2.0 DC-2.0		•	0.30 0.6 0.65 0.9	0.4 0.7 0.9 1.2	0.50 1.0 0.95 1.3	0.75 1.3 1.20 1.5	22 20	23 24	24 27	25 29	55 60	50 50	43 36 45 37	34 40	28 32	24 30	20 25	XX211 XX211	et es	2.45 2.45

Transfer DC to 2 GHz Low Video Leakage

path INSERTION LOSS (dB)														ISO	LATI	ON (dB)						
MSWT-4-20	DC-2.0 Tx-J1/J	0.9	1.2	1.1	1.5	1.25 1.8	1.45	2.2	18	25	28	29	51	44	34	27	26	21	19	15			
	J1/J2-R	(1.1	1.4	1.3	1.7	1.5 2.0	1.6	2.2	16	18	20	22	52	46	37	31	29	24	21	17	XX211	eu	3.45
	Tx-Rx												60	53	41	36	34	27	28	21			
A=DC to 100MHz B=100MHz to 500MHz									С	=5001	ЛHz t	o 100	OMH:	Z			D=	=1000	MHz to 2	1000	ЛHz		

control logic

		J					
Model		Contro	ol Ports	5	RF o	utputs	
Series	1	2	3	4	1	2	
KSW, KSWA	-V	0	_	_	On	Off	
MSW, MSWA	0	-V	_	_	Off	On	
MSWT					"On" I	Path	
					(other	paths ar	e "OFF")
	0	-V	-V	-V	Tx-J2		
	-V	0	-V	-V	Tx-J1		
	-V	-V	0	-V	Rx-J1		
	-V	-V	-V	0	Rx-J2		
	0	-V	0	-V	Tx-J2 8	k Rx-J1	
	-V	0	-V	0	Tx-J1 8	k Rx-J2	

pin connections

see case style o	outline drav	wings				
PORT	eh	ek	es	et	PORT	eu
RF IN	2	1	2	1	Tx	2
RF OUT 1	5	5	8	6	Rx	6
RF OUT 2	8	_	5	3	J1	4
+5V	_	_	_	_		
CONTROL 1	3	2	3	5	J2	8
CONTROL 2	1	3	1	4	CONTROL 1	1
GND EXT.	4,6,7	4,6,7,8	4,6,7	2,7,8	CONTROL 2	3
					CONTROL 3	5
					CONTROL 4	7

Application Note for Model MSWT-4-20 Transmit-Receive Switch:

The functional schematic diagram for a diversity application of the switch is shown in Figure 1, with the required external components including 4 independent diviers at the control ports. When operation as a transfer switch is desired only 2 drivers are needed, one connected to the V1 and V3 ports together, and the other connected to the V2 and V4 ports. In either case, two DC return paths are needed for the control voltages, represented by the ground symbols in the diagram. These returns must be via oppositely situated RF ports (Tx and Rx or J1 and J2), and can be furnished incidentally by the user's RF terminating devices themselves. However, if those devices are AC-coupled (that is, they contain DC blocking capacitors), then the shunt resistors shown in the diagram are needed. The resistors should be installed either at the Tx and Rx ports (connection shown as solid), or at J1 and J2 (shown dotted), with equal effect. If one external RF device has a DC return to ground, for example, then only one resistor is needed; it must be installed at the opposite RF port of the switch. The resistance of each of the external DC returns should be 20K ohms or less, for proper ON/OFF FETs.

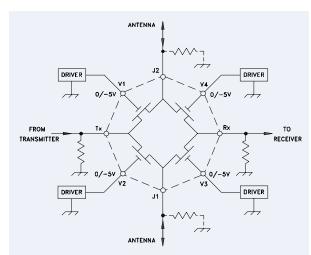


Figure 1. functional schematic diagram (Transmit-Receive application)

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